

## General Description

The MY3404 is the high cell density trenched N-CH MOSFET, which provides excellent  $R_{DS(ON)}$  and efficiency for most of the small power switching and load switch applications.

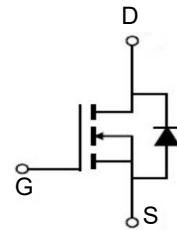
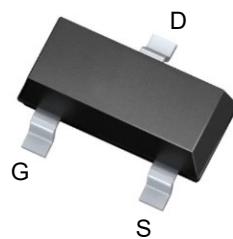


## Features

$V_{DSS}$	30	V
$I_D$	5.8	A
$R_{DS(ON)}(\text{at } V_{GS} = 10\text{V})$	25	$\text{m}\Omega$
$R_{DS(ON)}(\text{at } V_{GS} = 4.5\text{V})$	32	$\text{m}\Omega$

## Application

- Green Device Available
- Super Low Gate Charge
- Excellent CdV/dt effect decline



## Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
MY3404	SOT-23	3404	3000

## Absolute Maximum Ratings ( $T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-source Voltage	$V_{DS}$	30	V
Gate-source Voltage	$V_{GS}$	$\pm 20$	V
Drain Current	$I_D$	5.8	A
Pulsed Drain Current <sup>A</sup>	$I_{DM}$	23.4	A
Total Power Dissipation @ $T_c=25^\circ\text{C}$	$P_D$	1.5	W
Thermal Resistance Junction-to-Ambient <sup>B</sup>	$R_{\theta JA}$	-55~+150	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature Range	$T_J, T_{STG}$	-55~+150	$^\circ\text{C}$

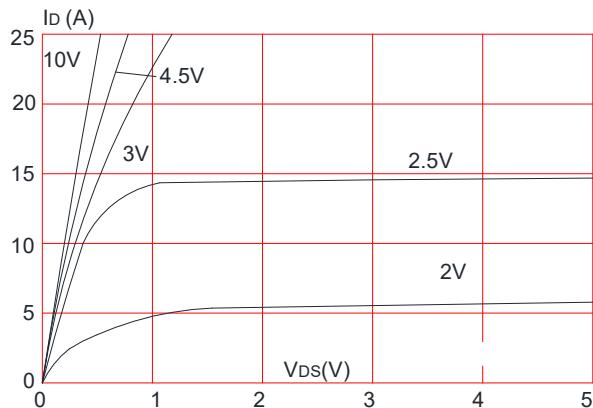
**Electrical Characteristics (T<sub>j</sub>=25 °C, unless otherwise noted)**

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
<b>Off Characteristic</b>						
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V, I <sub>D</sub> =250μA	30	-	-	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =30V, V <sub>GS</sub> =0V,	-	-	1.0	μA
I <sub>GSS</sub>	Gate to Body Leakage Current	V <sub>DS</sub> =0V, V <sub>GS</sub> =±20V	-	-	±100	nA
<b>On Characteristics</b>						
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA	1.0	1.5	2.5	V
R <sub>DS(on)</sub> note2	Static Drain-Source on-Resistance	V <sub>GS</sub> =10V, I <sub>D</sub> =5.5A	-	25	30	mΩ
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =4.5A	-	32	40	
<b>Dynamic Characteristics</b>						
C <sub>iss</sub>	Input Capacitance	V <sub>DS</sub> =15V, V <sub>GS</sub> =0V, f=1.0MHz	-	490	-	pF
C <sub>oss</sub>	Output Capacitance		-	79	-	pF
C <sub>rss</sub>	Reverse Transfer Capacitance		-	61	-	pF
Q <sub>g</sub>	Total Gate Charge	V <sub>DS</sub> =15V, I <sub>D</sub> =3A, V <sub>GS</sub> =10V	-	5.2	-	nC
Q <sub>gs</sub>	Gate-Source Charge		-	0.9	-	nC
Q <sub>gd</sub>	Gate-Drain("Miller") Charge		-	1.3	-	nC
<b>Switching Characteristics</b>						
t <sub>d(on)</sub>	Turn-on Delay Time	V <sub>DD</sub> =30V, I <sub>D</sub> =2A, R <sub>GEN</sub> =3Ω, V <sub>GS</sub> =10V	-	4.5	-	ns
t <sub>r</sub>	Turn-on Rise Time		-	2.5	-	ns
t <sub>d(off)</sub>	Turn-off Delay Time		-	14.5	-	ns
t <sub>f</sub>	Turn-off Fall Time		-	3.5	-	ns
<b>Drain-Source Diode Characteristics and Maximum Ratings</b>						
I <sub>s</sub>	Maximum Continuous Drain to Source Diode Forward Current		-	-	6	A
I <sub>SM</sub>	Maximum Pulsed Drain to Source Diode Forward Current		-	-	23.2	A
V <sub>SD</sub>	Drain to Source Diode Forward Voltage	V <sub>GS</sub> = 0V, I <sub>s</sub> =5.8A	-	-	1.2	V

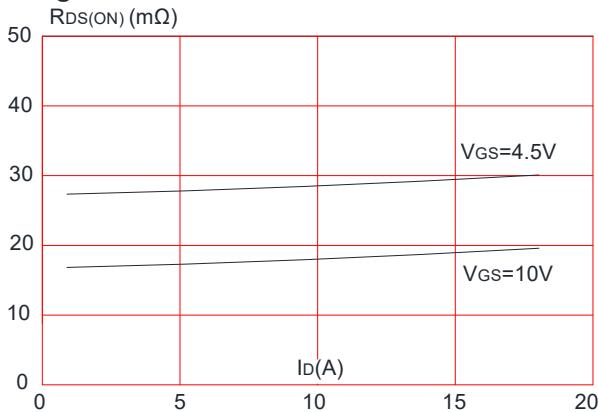
Notes: 1. Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature

2. Pulse Test: Pulse Width≤300μs, Duty Cycle≤0.5%

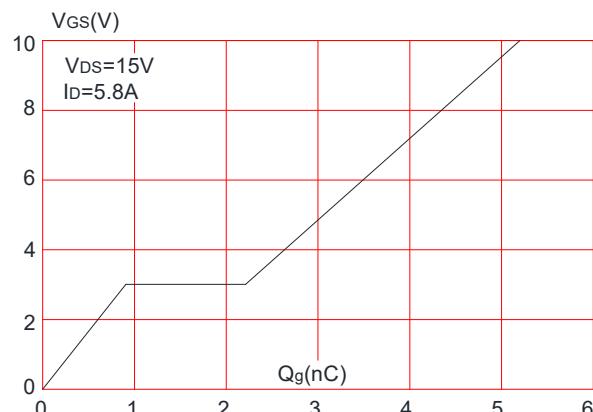
**Figure 1:** Output Characteristics



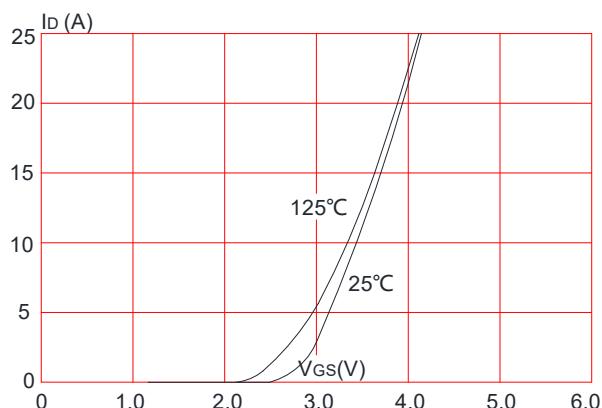
**Figure 3:** On-resistance vs. Drain Current



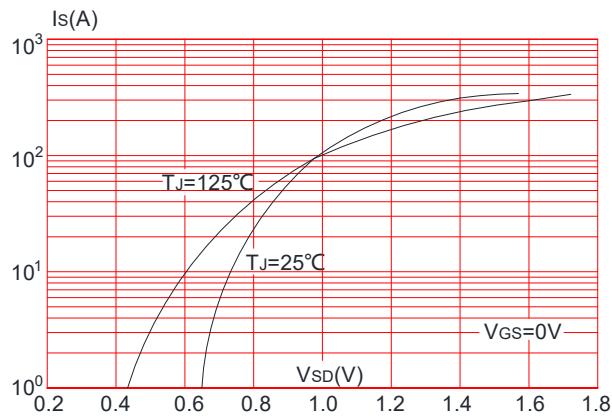
**Figure 5:** Gate Charge Characteristics



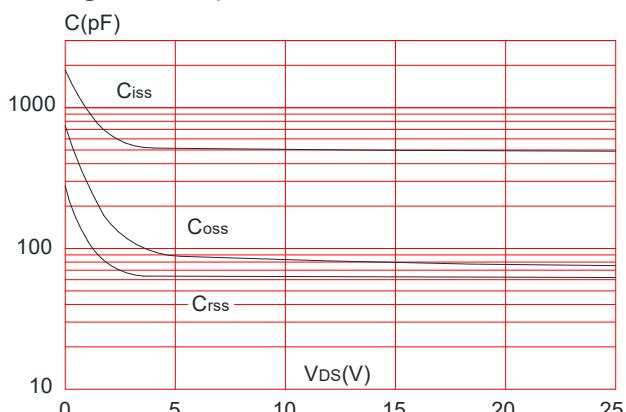
**Figure 2:** Typical Transfer Characteristics



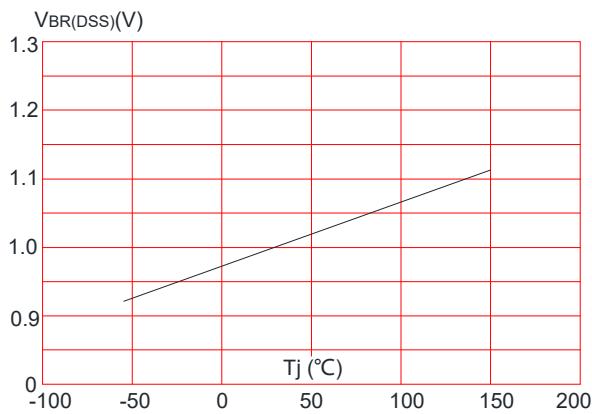
**Figure 4:** Body Diode Characteristics



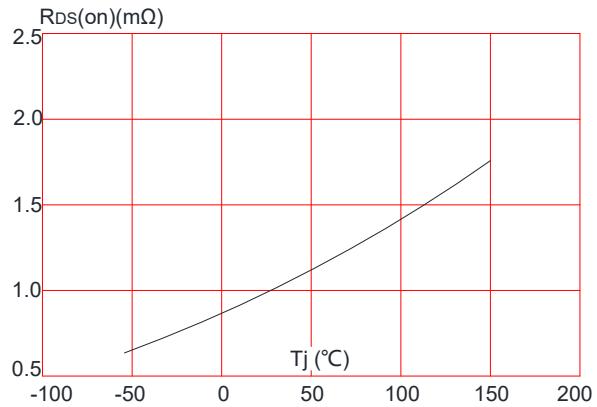
**Figure 6:** Capacitance Characteristics



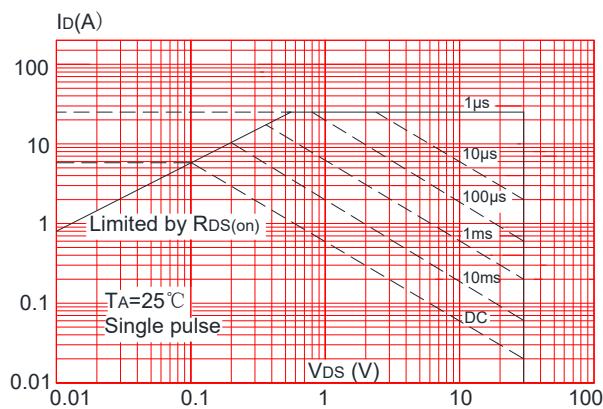
**Figure 7:** Normalized Breakdown Voltage vs. Junction Temperature



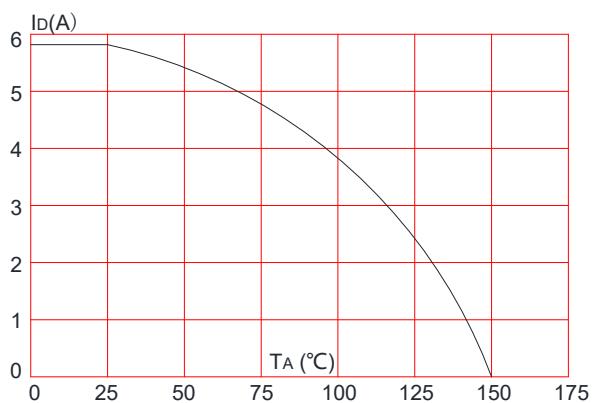
**Figure 8:** Normalized on Resistance vs. Junction Temperature



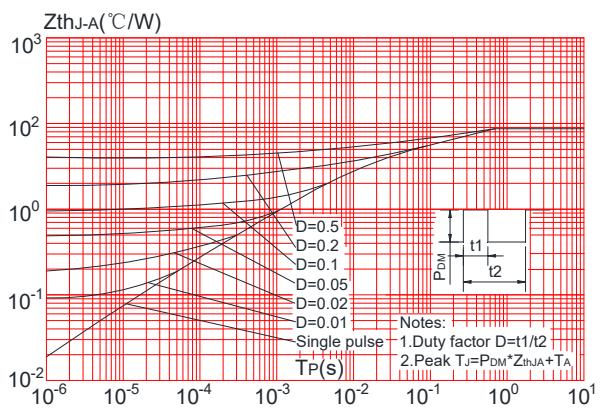
**Figure 9:** Maximum Safe Operating Area

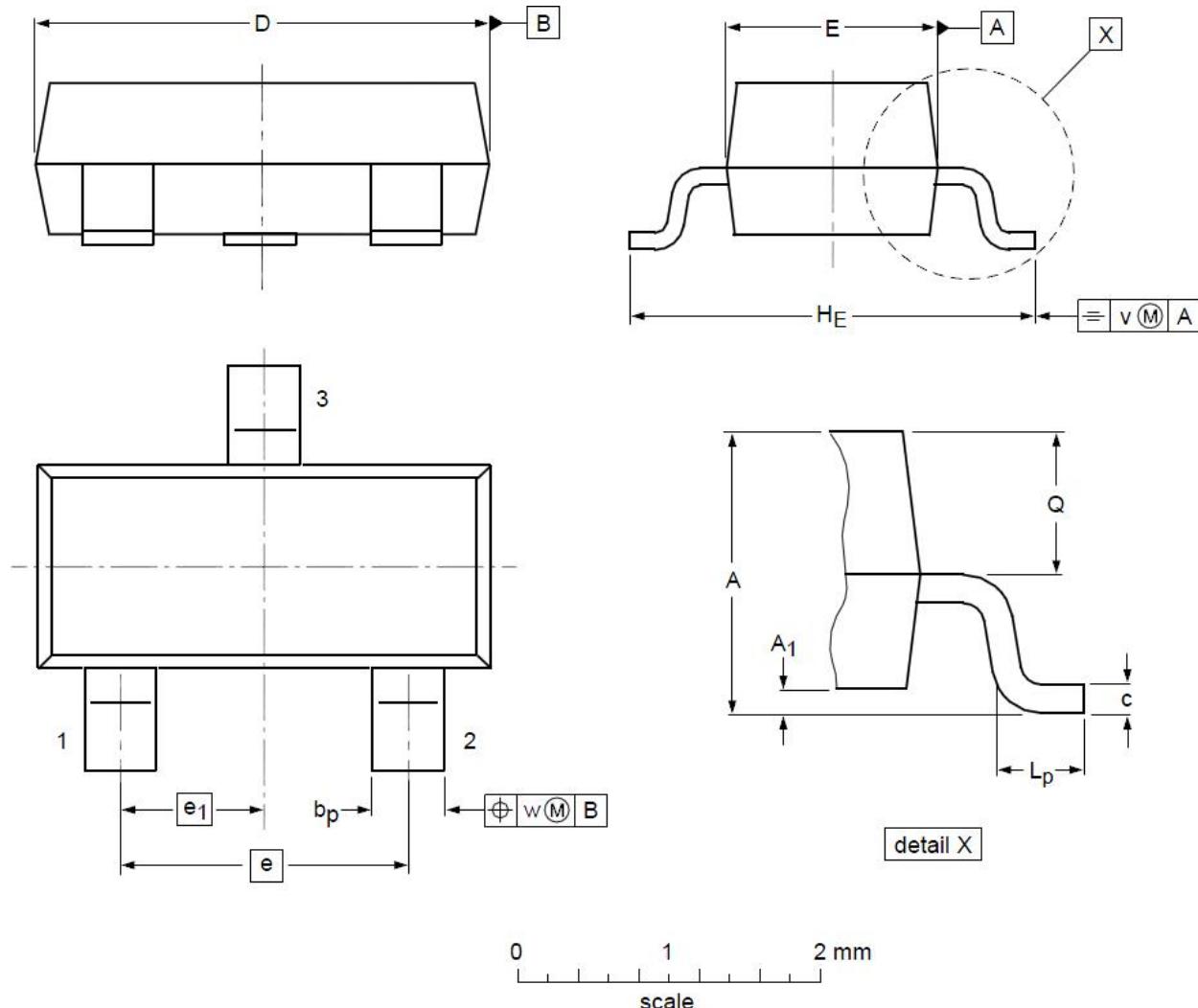


**Figure 10:** Maximum Continuous Drain Current vs. Ambient Temperature



**Figure 11:** Maximum Effective Transient Thermal Impedance, Junction-to-Ambient



**Package Mechanical Data-SOT-23**

**DIMENSIONS (unit : mm)**

Symbol	Min	Typ	Max	Symbol	Min	Typ	Max
<b>A</b>	0.90	1.01	1.15	<b>A<sub>1</sub></b>	0.01	0.05	0.10
<b>b<sub>p</sub></b>	0.30	0.42	0.50	<b>c</b>	0.08	0.13	0.15
<b>D</b>	2.80	2.92	3.00	<b>E</b>	1.20	1.33	1.40
<b>e</b>	--	1.90	--	<b>e<sub>1</sub></b>	--	0.95	--
<b>H<sub>E</sub></b>	2.25	2.40	2.55	<b>L<sub>p</sub></b>	0.30	0.42	0.50
<b>Q</b>	0.45	0.49	0.55	<b>v</b>	--	0.20	--
<b>w</b>	--	0.10	--				